Structure	Silicon Monolithic Bipolar IC
Appearance	SIL-9 Pin Plastic Package (Power Type with Fin)
Application	Low Frequency Amplifier
Function	BTL 4.0W x 1ch Power Amplifier with Standby Function and Volume Function

A	Absolute Maximum Ratings				
No.	Item	Symbol	Ratings	Unit	Note
1	Storage Temperature	Tstg	-55 ~ +150	°C	1
2	Operating Ambient Temperature	Topr	-25 ~ +70	°C	1
3	Operating Ambient Pressure	Popr	$1.013x10^5 \pm 0.61x10^5$	Pa	
4	Operating Constant Acceleration	Gopr	9,810	m/s^2	
5	Operating Shock	Sopr	4,900	m/s^2	
6	Supply Voltage	Vcc	14.4	V	2
7	Supply Current	Icc	1.0	A	
8	Power Dissipation	P_D	1.22	W	Ta=70·C

Operating Supply Voltage Range	Vcc	3.5V ~ 13.5V

Note 1) The temperature of all items shall be Ta=25°C except storage temperature and operating ambient temperature.

2) At no signal input.

B Electrical Characteristics

(Unless otherwise specified, the ambient temperature is 25°C±2•C, Vcc=8.0V, frequency=1kHz and R_L=8Ω.)

No	Item	Symbol	Test Circuit	Conditions	Limits			Unit	Note
					min	typ	max		
1	Quiescent Circuit Current	I_{CQ}	1	Vin=0V, Vol=0V	-	20	60	mA	
2	Standby Current	I_{STB}	1	Vin=0V, Vol=0V	-	1	10	μA	
3	Output Noise Voltage	V_{NO}	1	Rg=10kΩ, Vol=0V	-	0.10	0.4	mVrms	1
4	Voltage Gain	G_V	1	Po=0.5W, Vol=1.25V	31	33	35	dB	
5	Total Harmonic Distortion	THD	1	Po=0.5W, Vol=1.25V	-	0.10	0.5	%	
6	Maximum Power Output 1	P_O1	1	THD=10%, Vol=1.25V	2.4	3.0	-	W	
7	Maximum Power Output 2	P_O2	1	Vcc=9V THD=10%, Vol=1.25V	3.2	4.0	-	W	
8	Ripple Rejection Ratio	RR	1	Rg=10kΩ, Vol=0V Vr=0.5Vrms, fr=120Hz	30	50	-	dB	1
9	Output Offset Voltage	Voff	1	Rg=10kΩ, Vol=0V	-250	0	250	mV	
10	Volume Attenuation Ratio	Att	1	Po=0.5W, Vol=0V	70	85	-	dB	1
11	Middle Voltage Gain	G_{Vm}	1	Po=0.5W, Vol=0.6V	20.5	23.5	26.5	dB	

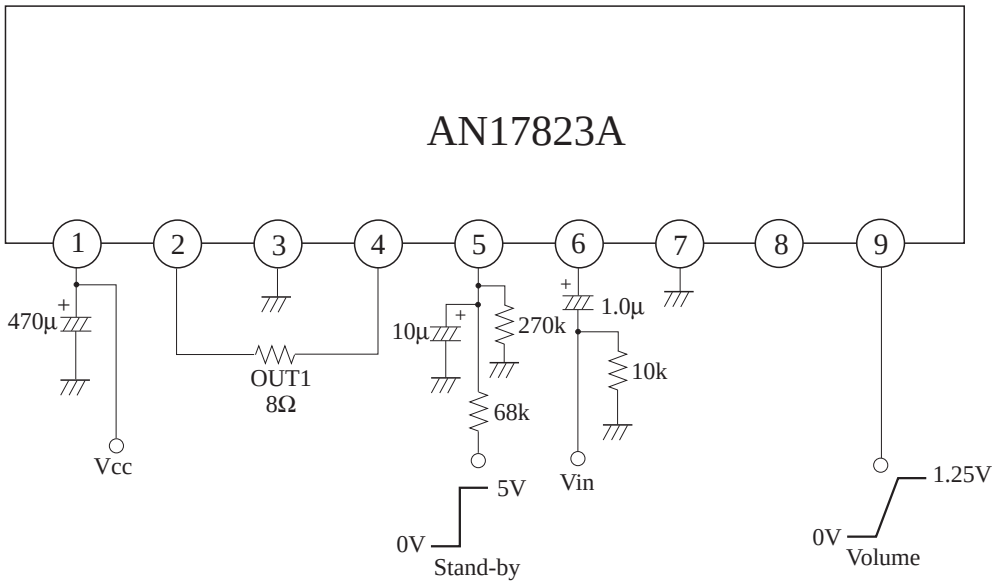
Note 1) For this measurement, use the BPF = 15Hz ~ 30kHz (12dB/OCT).

B	Electrical Characteristics	(Unless otherwise specified, the ambient temperature is 25°C±2°C, Vcc=8.0V, frequency=1kHz and R_L=8Ω.)							
No	Item	Symbol	Test Circuit	Conditions	Limits			Unit	Note
					min	typ	max		
1	Standby pin current	I_{STB2}	1	Vin=0V, V_{STB}=3V	-	-	25	μA	
2	Volume pin current	I_{VOL}	1	Vin=0V, Vol=0V	-12	-	-	μA	
3	Input Impedance	Z_i	1	Vin=±0.3V_{DC}	24	30	36	kΩ	

Note) The above characteristics are reference values determined for IC design, but not guaranteed values for shipping inspection. If problems were to occur, counter measures will be sincerely discussed.

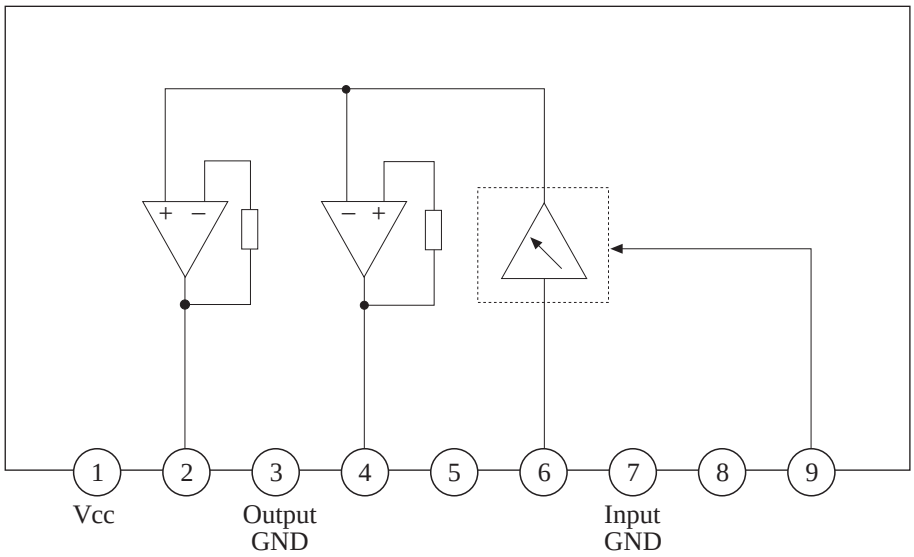
(Description of test circuit and test method)

Test Circuit 1



Note) If the standby pin is open or 0V, the IC is on standby state.
The IC is in the state of volume minimum if the Volume pin is ground.
The IC is in the state of volume maximum if the Volume pin is open.

Circuit Function Block Diagram



Pin Descriptions

Pin No.	Description
1	Vcc
2	Ch Output (+)
3	GND (Output)
4	Ch Output (-)
5	Standby
6	Ch Input
7	GND (Input)
8	N.C
9	Volume

Note) Do not apply voltage or current to NC pin from outside.

Prepared		Product Specifications	Ref No.	E
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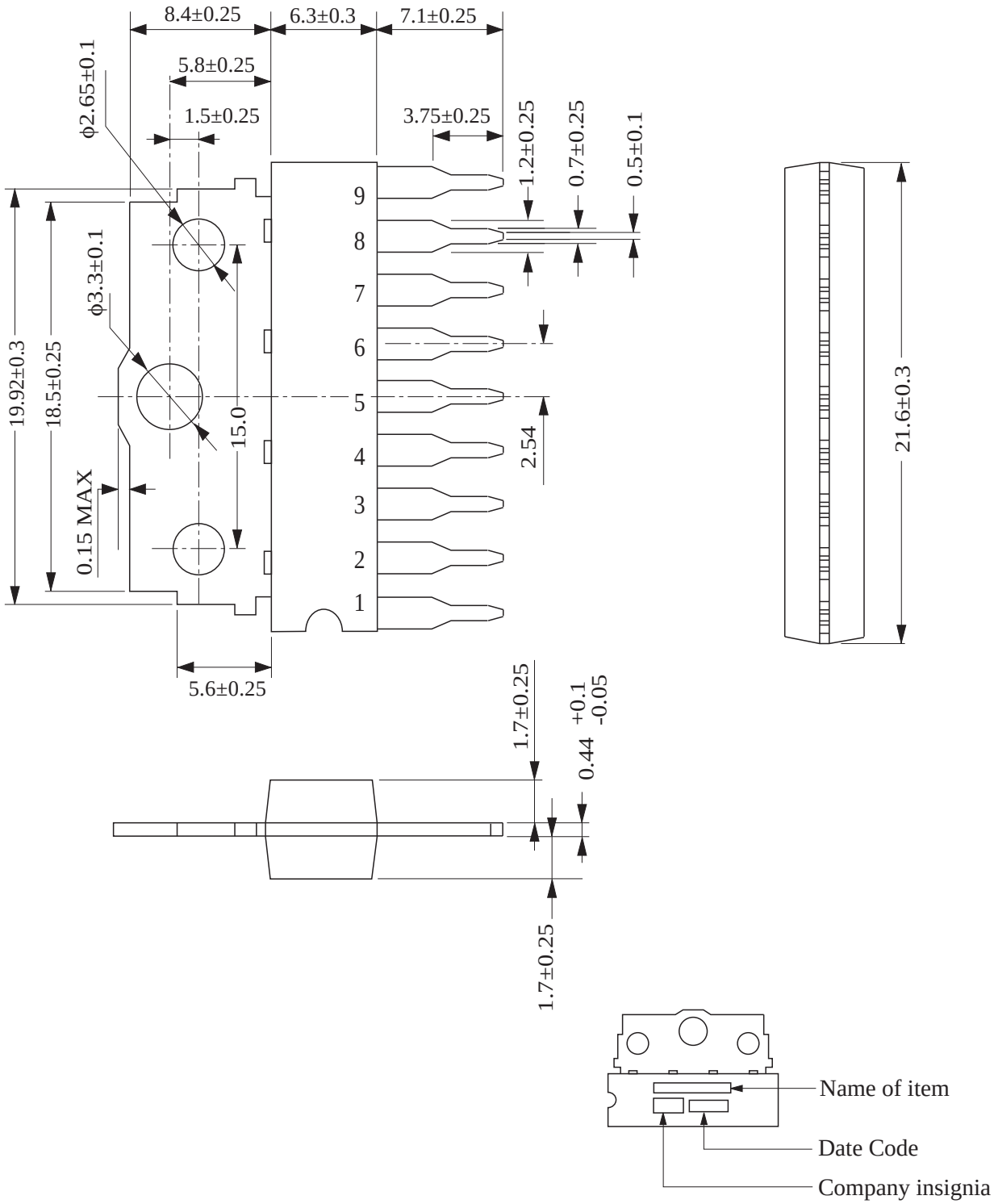
Package Name	F - 9S

Unit : mm

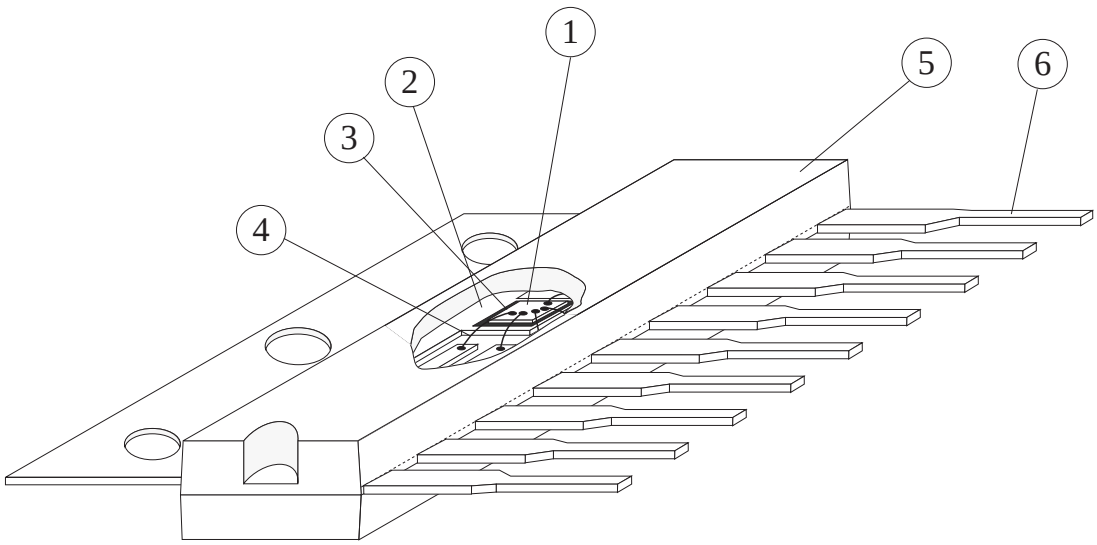


Eff. Date	Eff. Date	Eff. Date	Eff. Date
06-MAR-2002			

(Structure Description)

Chip surface passivation	[SiN,] PSG, Others ( )	(1)
Lead frame material	Fe group, [Cu group,] Others ( )	(2), (6)
Inner lead surface process	[Ag plating,] Au plating, Others ( )	(2)
Outer lead surface process	[Solder plating,] Solder dip, Others ( )	(6)
Chip mounting method	Ag paste, Au-Si alloy, [Solder,] Others ( )	(3)
Wire bonding method	[Thermalsonic bonding,] Others ( )	(4)
Mold material	Epoxy, Others ( )	(5)
Molding method	[Transfer mold,] Multiplunger mold, Others ( )	(5)

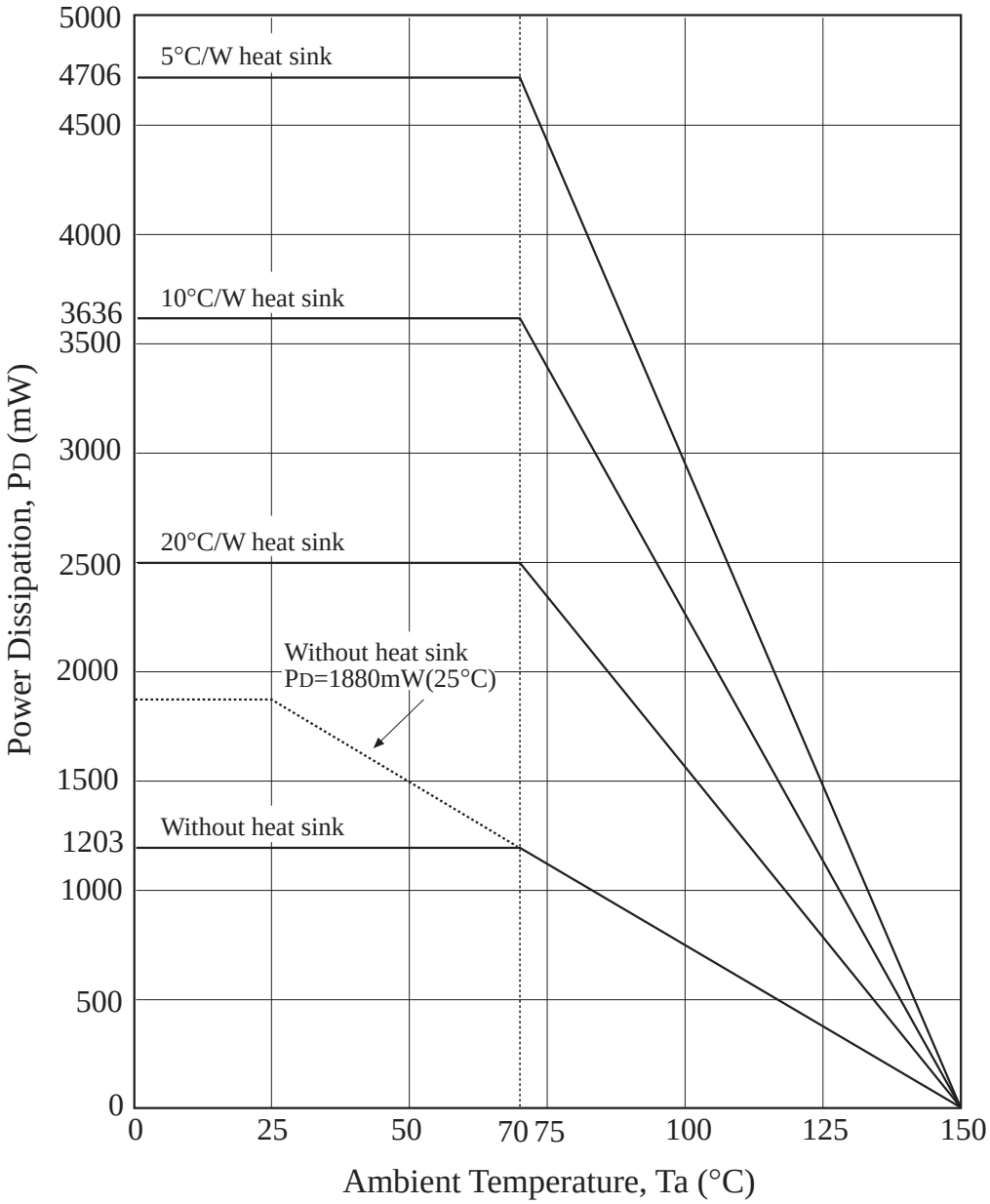
Package 9-SIP(F)



(Rth(j-c) = 12.0°C/W
Rth(j-a) = 66.5°C/W)

F-9S Package Power Dissipation

PD - Ta



(Precautions for use)

1) Make sure that the IC is free of any pin short-circuiting, ground short, and load short-circuiting.

2) Ground the radiation fin so that there will be no difference in electric potential between the radiation fin and ground.

3) The thermal protection circuit operates at a Tj of approximately 150°C. The thermal protection circuit is reset automatically when the temperature drops.

4) Make sure that the heat radiation design is effective enough if the Vcc is comparatively high or the IC operates high output power.

5) Connect only ground pin for signal sources to the signal GND pin of the amplifier on the previous stage.